

Diffusion Gradient in Thin Films (DGT) from single ligand systems to mixtures.

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Plants survival: Nutrients availability

Micronutrients Uptake: Fe



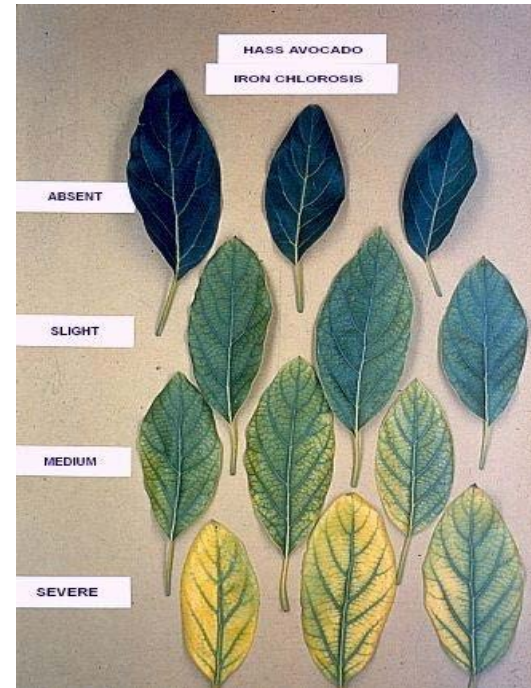
Plant strategy for iron uptake:

- Uptake of **free iron** (Fe^{+3})
- Generation of siderophores(via chelating agents)

Lack of free iron (Fe^{+3}) in soil?

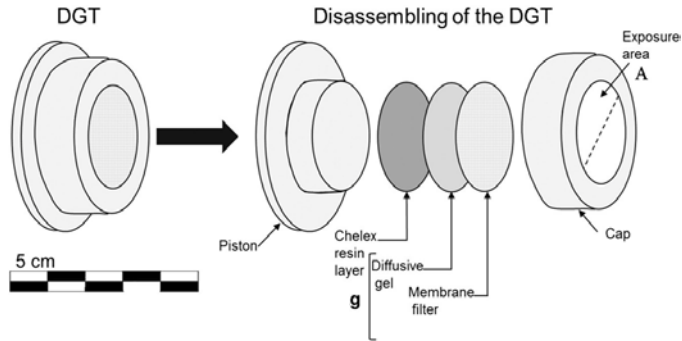


Iron chlorosis,
Yellowing of
plants leaves



DGT technique

Use in soils

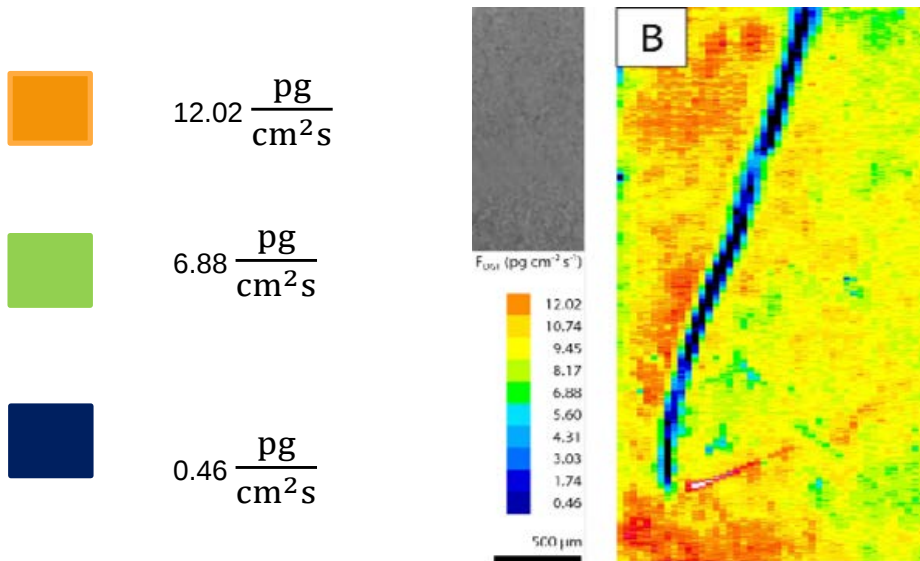


Chelex Resin → Metal accumulation → Elution with an acid solution

ICP-MS/ ICP-OES → Effective concentration (c_{DGT})

DGT applications

Screening of phosphate uptake by a maize root



J. Santner et al. *Analytica Chimica Acta* 878 (2015) 9–42.

E. D. Amato, et al *Environmental Science & Technology* 2016 50 (6), 3055-3064

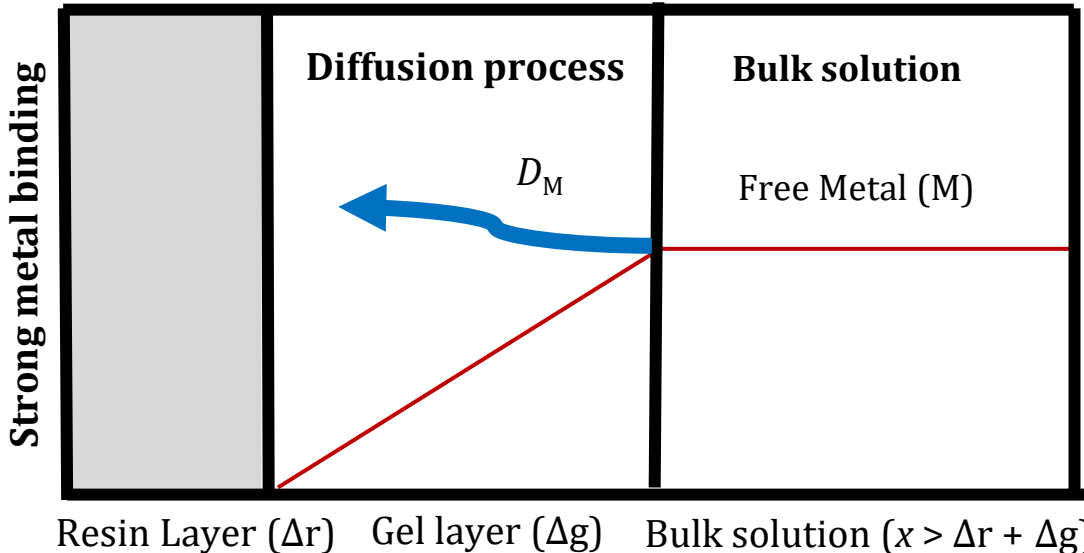
How metal accumulation (n) is computed only considering free metal ion?

Metal accumulation $J = \frac{D_M c_M^*}{g} \quad n = AtJ$

- **Free metal concentration drops to zero** due to the **strong and fast** binding of M to resin beads.



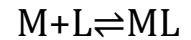
- **Diffusion process** of free metal ion along the diffusive **gel**



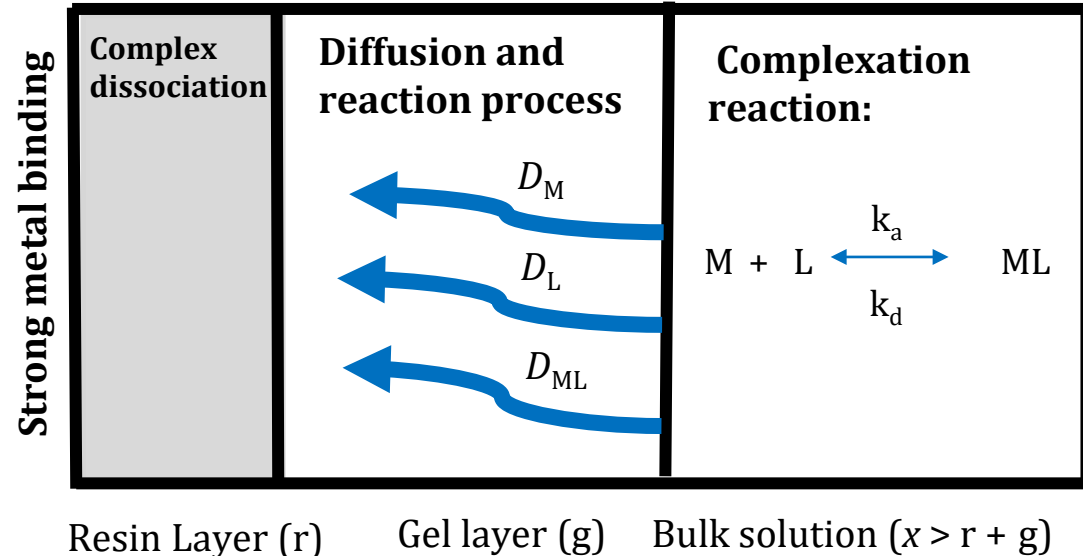
How c_{DGT} is related to the concentration of species?

Metal accumulation $J = \frac{D_{\text{M}} c_{\text{DGT}}}{g} \quad n = AtJ$

- **Diffusion-reaction processes** along the diffusive gel



- The **free metal concentration drops to zero** due to the **strong and fast** binding of M to resin beads.



Objectives

- Interpretation of the effective c_{DGT} concentration in terms of species of the natural media.
- Design and test some strategies in experimental systems where using DGT devices with different “g” and “r” thicknesses we could be able to determine concentrations/mobilities or labilities of species present in natural waters.

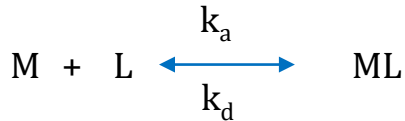
Tools to fulfill the objectives

- To develop an algorithm to compute the concentration profiles of system mixtures containing mixtures of ligands in high and low ionic strength conditions (using Nernst-Planck equation).
- To develop approximate analytical expressions to compute the flux contribution of free metal ion and its complexes at the resin layer for systems of 2 ligands or more.
- To develop simple approximate analytical expressions to compute the lability degree of each metal species for an experimental designed system.
- To conduct experimental measurements in simple mixture systems.

Methodology

Application of Finite Element Method (FEM) on transport equations

Considering the simplest complexation reaction (single ligand system):



$$r > x > r + g \quad \frac{\partial c_M}{\partial t} = D_M \frac{\partial^2 c_M}{\partial x^2} - k_a c_M c_L + k_d c_{ML}$$

$$0 > x > r \quad \frac{\partial c_M}{\partial t} = D_M \frac{\partial^2 c_M}{\partial x^2} - k_a c_M c_L + k_d c_{ML} - k_{aR} c_M c_R + k_{dR} c_{MR}$$

$$0 > x > r + g \quad \frac{\partial c_L}{\partial t} = D_L \frac{\partial^2 c_L}{\partial x^2} - k_a c_M c_L + k_d c_{ML}$$

$$0 > x > r + g \quad \frac{\partial c_{ML}}{\partial t} = D_{ML} \frac{\partial^2 c_{ML}}{\partial x^2} + k_a c_M c_L - k_d c_{ML}$$

D_M : metal diffusion coefficient.

D_{ML} : complex diffusion coefficient.

D_L : ligand diffusion coefficient.

k_a : association rate constant

k_d : dissociation rate constant 9

DGT initial and boundary conditions

$$t = 0 \quad c_i(r + g, t) = c_i^* \quad c_R(x \leq r, t) = c_{TR}$$

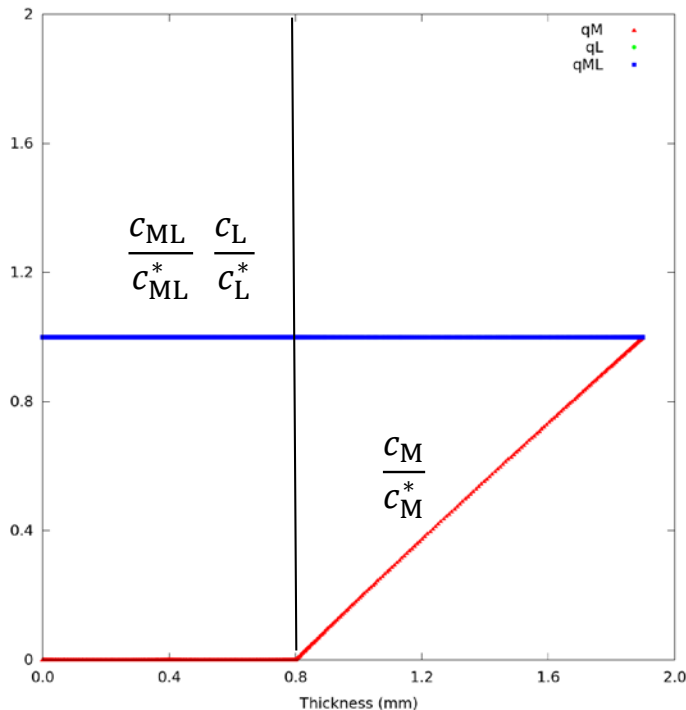
$$t = 0 \quad c_i(x < r + g, t) = 0 \quad R \equiv \text{Chelex Resin}$$

$$x = 0 \quad D_i \frac{\partial c_i(x, t)}{\partial x} = 0$$

$$x = r \quad D_i \frac{\partial c_i(x, t)}{\partial x} \Big|_{(x=r^-)} = D_i \frac{\partial c_i(x, t)}{\partial x} \Big|_{(x=r^+)}$$

$$x \geq r + g \quad c_i(x, t) = c_i^*$$

Simulations in excess of ligand conditions



Resin layer (r)

Gel layer (g)

$$K = 21322$$

$$k_a = 10^{-2} \frac{m^3}{mol}$$

$$k_d = 46.9 \times 10^{-8} s^{-1}$$

$$D_M = D_{ML} = D_L \equiv \frac{m^2}{s}$$

Total metal flux at $x=r$

$$J_1 = D_M \frac{c_M^*}{g}$$

Simulations in excess of ligand conditions

$$K = 21322$$

$$k_a = 10^6 \frac{m^3}{mol} \quad D_M = D_{ML} = D_L$$

$$k_d = 46.9 s^{-1}$$

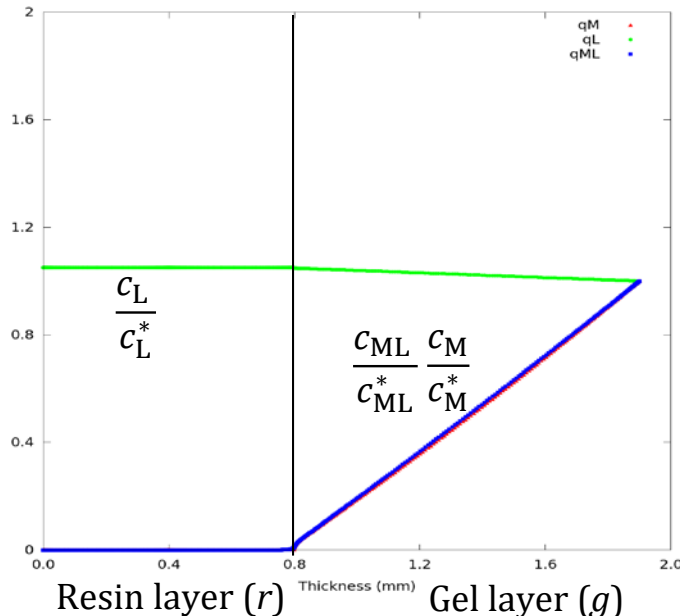
For fully labile complexes

Local Equilibrium

$$\frac{c_{ML}}{c_{ML}^*} = \frac{c_M}{c_M^*}$$

Total metal flux at $x=r$

$$J_3 = D_M \frac{c_M^*}{g} + D_{ML} \frac{c_{ML}^*}{g}$$

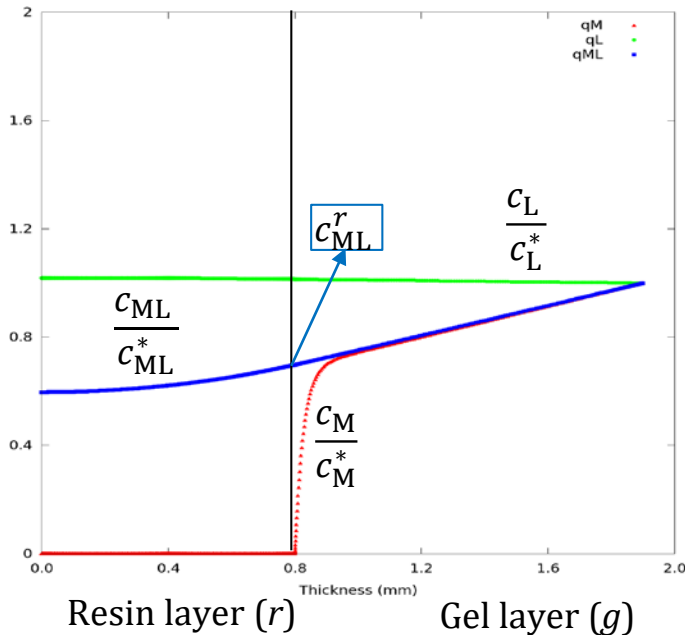


Simulations in excess of ligand conditions

$$K = 21322$$

$$k_a = 10^2 \frac{\text{m}^3}{\text{mol}} \quad D_M = D_{ML} = D_L$$

$$k_d = 46.9 \times 10^{-4} \text{s}^{-1}$$



Total metal flux at $x=r$

$$J_2 = D_M \frac{c_M^*}{g} + D_{ML} \frac{c_{ML}^* \xi}{g}$$

$\xi \equiv$ lability degree

$$\xi = 1 - \frac{c_{ML}^r}{c_{ML}^*}$$

Comparison of total metal flux at $x=r$ with previous simulations

$$J_3 > J_2 > J_1$$

For a system of n ligands

Metal accumulation

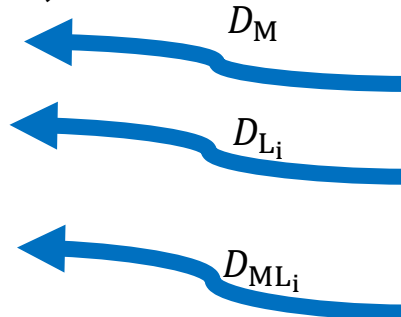
$$n = AtJ$$

$$J = \frac{D_M c_M^*}{\Delta g} + \sum_{i=1}^N \frac{D_{ML_i} c_{ML_i}^*}{\Delta g} \xi_i$$

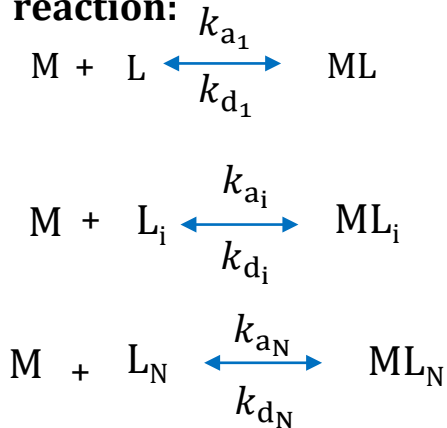
Strong metal binding

Complex dissociation

Diffusion process for
 $i=1,n$



Complexation
reaction:



Resin Layer (r)

Gel layer (g)

Bulk solution ($x > r + g$)

For a system of n ligands

Analytical expression for total metal flux.

$$J = \frac{D_M c_M^*}{g} + \sum_{i=1}^N \frac{D_{ML_i} c_{ML_i}^*}{g} \xi_i$$

Expression for total metal flux considering an effective metal concentration.

$$J = \frac{D_M c_{DGT}}{g}$$

Relationship of effective metal concentration (c_{DGT}) with the concentration of the species of this system.

$$c_{DGT} = c_M^* + \sum_{i=1}^N \frac{D_{ML_i}}{D_M} c_{ML_i}^* \xi_i$$

Work Plan

Topics	Time Waste
Formation courses	2 months
Concentration profiles of mixture systems. Dependence of the lability degree on the composition of the mixture	6 -8 months
Effect of low ionic strength in DGT accumulations from first principles	6 -8 months
DGT measurements in mixture model systems and in natural waters.	6-8 months
Research Stay	3 months
Articles and Thesis	7 months

Acknowledgements

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- Support from UdL for the scholarship of 3 years is gratefully acknowledged
- Thanks for your attention!